NSN 5961-01-373-7056

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-373-7056 **Inclosure Material:** Plastic **Overall Length:** Between 2.8 millimeters and 3.0 millimeters **Overall Height:** 1.100 millimeters **Overall Width:** Between 1.2 millimeters and 1.4 millimeters Joint Electronic Device Engineering Council/jedec/case Outline Designation: Sot-123 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 28.0 reverse voltage, peak **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current preset **Capacitance Rating In Picofarads:** 2.0 **Maximum Operating Tempurature Per Measurement Point:** 85.0 degrees celsius junction **Special Features:** One terminal not connected; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No